20 STERN AVE.

SPRINGFIELD, NEW JERSEY 07081

U.S.A.

## **VE08X – VE106X**

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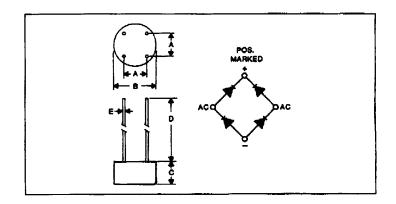
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## 1 Amp Fast Recovery Time Epoxy Bridge Rectifiers

200 Nanosecond Reverse Recovery Time 50V, 100V, 200V, 400V, and 600V V<sub>RRM</sub> Ratings Glass Passivated Silicon Chips

LTRL	INCHES	MILLIMETERS	
A	.185215	4,70-5,46	
В	.350-,365	8.89-9.27	
ČΙ	.190215	4,83-5,46	
Ď	1.0 MIN.	25.4 MIN.	
Ē	.022028 DIA.	.558-,711	



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	VEOSX	VE18X	VE28X	VE48X	VE68X	VE86X	VE108X	UNITS
DC Blocking Voltage, Working Peak Reverse Voltage, Peak Repetitive Reverse Voltage,	V <sub>RM</sub> V <sub>RMM</sub> V <sub>RMM</sub>	50	100	200	400	600	800	1000	Volts
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	Volts
Peak Surge Current, ½ Cycle at 60 Hz, (Non-Rep) and T <sub>A</sub> = 40°C (Fig.2)	I <sub>FSM</sub>	17							Amps
Peak Surge Current, 1 sec. at 60 Hz and T <sub>A</sub> = 40°C (Fig. 2)	IFRM	FRM 3						Amps	
Avg. Forward Current at T <sub>c</sub> = 40°C, (Fig. 1)	) la		1						Amps
Junction Operating and Storage Temperature Range	TJ, Tsrg	- 50 to + 135						.c	
Max. Soldering Temperature & Time				1	0 Sec. at 26	5°C		-	

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL			UNITS
Maximum Instantaneous Forward Voltage Drop (per diode) at 1 Amp (Fig. 3)	V <sub>PM</sub>	1.5	1.6	Volts/ Leg
Maximum Reverse Recovery Time I <sub>F</sub> = 1 Amp, I <sub>R</sub> = 2 Amp, I <sub>RR</sub> = 0.5 Amp	t,	200		nsec
Maximum Reverse Current at Rated V <sub>RM</sub>	I <sub>RM</sub>	10		μΑ
Maximum Reverse Current at Rated V <sub>RM</sub> at T <sub>A</sub> = 125°C (Fig. 4)	IRM	2		mA
Insulation Strength Circuit to Case (Min.)		2000		Vdc
Thermal Resistance (Typ) Junction To Ambient	Rew	45		'C/W

VE Series Bridges have been recognized under the components program of Underwriters Laboratones, Inc.



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